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Valleytronics. The valley Hall effect in MoS₂ transistors

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1337	Microscopic Origin of the Valley Hall Effect in Transition Metal Dichalcogenides Revealed by Wavelength-Dependent Mapping.		
1336	Link to hereditary melanoma brightens mood for p16 gene. <i>Science</i> , 1994 , 265, 1364-5	33.3	2
1335	Book review: Bloody Nasty People. 2013 , 60, 445-447		
1334	Valley-polarized insulating states in zigzag silicene nanoribbons. 2014 , 1, 045009		12
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1332	Magneto-optical spectra of transition metal dichalcogenides: A comparative study. 2014 , 105, 222411		12
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